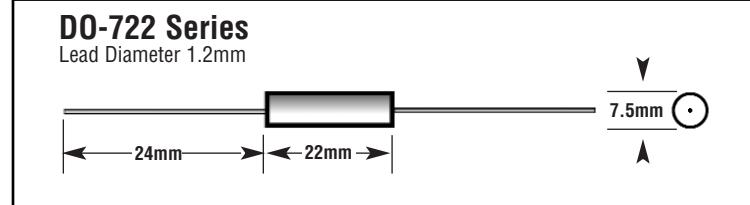
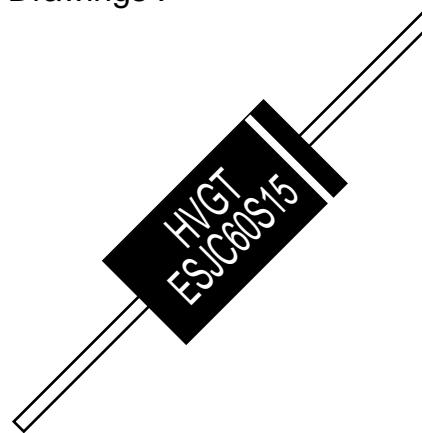


High reliability resin molded type high voltage diode in small size package which is sealed a multilayed mesa type silicon chip by epoxy resin.

■ Outline Drawings :



■ Features

- High speed switching
- Epoxy resin molded in vacuum, Have anticorrosion in the surface
- High surge resistivity for CRT discharge
- High reliability design
- Avalanche characteristic

■ Applications

- X light Power supply
- Laser
- Voltage doubler circuit
- Microwave emission power
- General purpose high voltage rectifier, Voltage multiplier assembly.

■ Maximum Ratings and Characteristics

• Absolute Maximum Ratings

Items	Symbols	Condition	ESJC60S15	Units
Repetitive Peak Reverse Voltage	V_{RRM}	Ta=25°C, $I_R = 0.1\text{mA}$	15	kV
Average Output Current	I_o	Ta=25°C, Resistive Load	0.5	A peak
Surge Current	I_{FSM}	Ta=25°C, 8.3msec, half sine	30	A peak
Junction Temperature	T_j		125	°C
Allowable Operation Case Temperature	T_c		125	°C
Storage Temperature	T_{stg}		-40 to +125	°C

• Electrical Characteristics (Ta=25°C Unless otherwise specified)

Items	Symbols	Conditions	ESJC60S15	Units
Maximum Forward Voltage Drop	V_F	at 25°C, at: I_F	16	V
Maximum Reverse Current	I_{R1}	at 25°C, $V_R = V_{RRM}$	5.0	uA
	I_{R2}	at 100°C, $V_R = V_{RRM}$	50	uA
Maximum Reverse Recovery Time	T_{rr}	at 25°C; $I_F = 0.5I_R$; $I_R = I_F(AV)$; $I_{rr} = 0.25I_R$	--	nS
Junction Capacitance	C_j	at 25°C; $V_R = 0V$, $f = 1\text{MHz}$	--	pF